SCAS590 - DECEMBER 1997

- High-Speed, Low-Skew 1-to-10 Clock Buffer for SDRAM (Synchronous DRAM) Clock Buffering Applications
- Output Skew, t<sub>sk(o)</sub>, Less Than 250 ps
- Pulse Skew, t<sub>sk(p)</sub>, Less Than 500 ps
- Supports up to Two Unbuffered SDRAM DIMMs (Dual Inline Memory Modules)
- I<sup>2</sup>C Serial Interface Provides Individual Enable Control for Each Output
- Operates at 3.3 V
- Distributed V<sub>CC</sub> and Ground Pins Reduce Switching Noise
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015
- Packaged in 28-Pin Shrink Small Outline (DB) Package

#### **DB PACKAGE** (TOP VIEW) V<sub>CC</sub> □ 10 28 Vcc 2 27 2Y3 1Y0 🗆 1Y1 □ 3 26 2Y2 4 25 ☐ GND GND [ 5 24 $V_{CC}$ V<sub>CC</sub> □ 1Y2 🗆 6 23 **□** 2Y1 7 22 1Y3 □ □ 2Y0 8 21 GND □ ☐ GND 9 $A \square$ 20 III OE 19 10 $\perp$ $\vee$ <sub>CC</sub> $V_{CC} \square$ 3Y0 □ 11 18 GND □ 12 17 ☐ GND ☐ GND V<sub>CC</sub> □ 13 16 SDATA [ 14 15 ☐ SCLOCK

### description

The CDC319 is a high-performance clock buffer that distributes one input (A) to 10 outputs (Y) with minimum skew for clock distribution. The CDC319 operates from a 3.3-V power supply, and is characterized for operation from 0°C to 70°C.

The device provides a standard mode (100K-bits/s)  $I^2C$  serial interface for device control. The implementation is as a slave/receiver. The device address is specified in the  $I^2C$  device address table. Both of the  $I^2C$  inputs (SDATA and SCLOCK) provide integrated pullup resistors (typically 140 k $\Omega$ ) and are 5-V tolerant.

Three 8-bit  $I^2C$  registers provide individual enable control for each of the outputs. All outputs default to enabled at powerup. Each output can be placed in a disabled mode with a low-level output when a low-level control bit is written to the control register. The registers are write only and must be accessed in sequential order (i.e., random access of the registers is not supported).

The CDC319 provides 3-state outputs for testing and debugging purposes. The outputs can be placed in a high-impedance state via the output-enable (OE) input. When OE is high, all outputs are in the operational state. When OE is low, the outputs are placed in a high-impedance state. OE provides an integrated pullup resistor.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Intel is a trademark of Intel Corporation

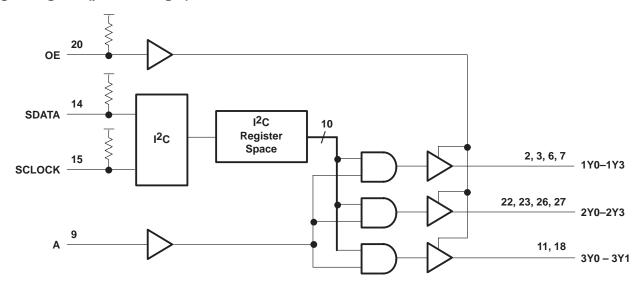


### **FUNCTION TABLE**

INP	JTS		OUTPUTS	
OE	Α	1Y0-1Y3	2Y0-2Y3	3Y0-3Y1
L	Х	Hi-Z	Hi-Z	Hi-Z
Н	L	L	L	L
Н	Н	н†	н†	н†

<sup>†</sup>The function table assumes that all outputs are enabled via the appropriate I2C configuration register bit. If the output is disabled via the appropriate configuration bit, then the output is driven to a low state, regardless of the state of the A input.

# logic diagram (positive logic)



### **Terminal Functions**

TERMINAL		1/0	DESCRIPTION				
NAME	NO.	1/0	DESCRIPTION				
1Y0-1Y3	2, 3, 6, 7	0	3.3-V SDRAM byte 0 clock outputs				
2Y0-2Y3	22, 23, 26, 27	0	3.3-V SDRAM byte 1 clock outputs				
3Y0-3Y1	11, 18	0	3.3-V clock outputs provided for feedback control of external PLLs (phase-locked loops)				
А	9	I	Clock input				
OE	20	ı	Output enable. When asserted, OE puts all outputs in a high-impedance state. A nominal $140$ -k $\Omega$ pullup resistor is internally integrated.				
SCLOCK	15	I	I <sup>2</sup> C serial clock input. A nominal 140-kΩ pullup resistor is internally integrated.				
SDATA	14	I/O	Bidirectional I <sup>2</sup> C serial data input/output. A nominal 140-k $\Omega$ pullup resistor is internally integrated.				
GND	4, 8, 12, 16, 17, 21, 25		Ground				
VCC	1, 5, 10, 13, 19, 24, 28		3.3-V power supply				



### I<sup>2</sup>C DEVICE ADDRESS

A7	A6	A5	A4	А3	A2	A1	A0 (R/W)
Н	Н	L	Н	L	L	Н	_

### I<sup>2</sup>C BYTE 0-BIT DEFINITION<sup>†</sup>

BIT	DEFINITION	DEFAULT VALUE
7	Reserved	Н
6	Reserved	Н
5	Reserved	Н
4	Reserved	Н
3	1Y3 enable (pin 7)	Н
2	1Y2 enable (pin 6)	Н
1	1Y1 enable (pin 3)	Н
0	1Y0 enable (pin 2)	Н

TWhen the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.

### I<sup>2</sup>C BYTE 1-BIT DEFINITION<sup>†</sup>

BIT	DEFINITION	DEFAULT VALUE
7	2Y3 enable (pin 27)	Н
6	2Y2 enable (pin 26)	Н
5	2Y1 enable (pin 23)	Н
4	2Y0 enable (pin 22)	Н
3	Reserved	Н
2	Reserved	Н
1	Reserved	Н
0	Reserved	Н

<sup>†</sup>When the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.

### I<sup>2</sup>C BYTE 2-BIT DEFINITION<sup>†</sup>

BIT	DEFINITION	DEFAULT VALUE
7	3Y1 enable (pin 18)	Н
6	3Y0 enable (pin 11)	Н
5	Reserved	Н
4	Reserved	Н
3	Reserved	Н
2	Reserved	Н
1	Reserved	Н
0	Reserved	Н

<sup>†</sup> When the value of the bit is high, the output is enabled. When the value of the bit is low, the output is forced to a low state. The default value of all bits is high.



SCAS590 - DECEMBER 1997

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V <sub>CC</sub>	0.5 V to 4.6 V
Input voltage range, V <sub>I</sub> (see Note 1)	0.5 V to 4.6 V
Input voltage range, V <sub>I</sub> (SCLOCK, SDATA) (see Note 1)	0.5 V to 6.5 V
Output voltage range, V <sub>O</sub> (SDATA) (see Note 1)	0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, VO0	.5 V to V <sub>CC</sub> +0.5 V
Current into any output in the low state (except SDATA), IO	48 mA
Current into SDATA in the low state, I <sub>O</sub>	12 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0) (SCLOCK)	–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0) (SDATA)	–50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2)	
Storage temperature range, T <sub>stq</sub>	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.

# recommended operating conditions (see Note 3)

			MIN	TYP	MAX	UNIT
Vcc	3.3-V core supply voltage		3.135		3.465	V
		A, OE	2		V <sub>CC</sub> +0.3	V
VIH	High-level input voltage	SDATA, SCLOCK (see Note 3)	2.2		5.5	V
		A, OE	-0.3		0.8	V
$V_{IL}$	Low-level input voltage	SDATA, SCLOCK (see Note 3)	0		1.04	V
loн	High-level output current	Y outputs			-24	mA
loL	Low-level output current	Y outputs			24	mA
R <sub>I</sub>	Input resistance to V <sub>CC</sub>	SDATA, SCLOCK (see Note 3)		140		kΩ
f(SCL)	SCLOCK frequency				100	kHz
t(BUS)	Bus free time		4.7			μs
t <sub>su(START)</sub>	START setup time		4.7			μs
<sup>t</sup> h(START)	START hold time		4			μs
tw(SCLL)	SCLOCK low pulse duration		4.7			μs
tw(SCLH)	SCLOCK high pulse duration		4			μs
<sup>t</sup> r(SDATA)	SDATA input rise time				1000	ns
<sup>t</sup> f(SDATA)	SDATA input fall time				300	ns
t <sub>su(SDATA)</sub>	SDATA setup time		250			ns
th(SDATA)	SDATA hold time		0			ns
t <sub>su(STOP)</sub>	STOP setup time		4			μs
$T_A$	Operating free-air temperature	·	0		70	°C

NOTE 3: The CMOS-level inputs fall within these limits:  $V_{IH}$  min =  $0.7 \times V_{CC}$  and  $V_{IL}$  max =  $0.3 \times V_{CC}$ .



# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CON	DITIONS	MIN	TYP	MAX	UNIT	
VIK	Input clamp voltage		V <sub>CC</sub> = 3.135 V,	I <sub>I</sub> = -18 mA			-1.2	V	
Vон	High-level output voltage	Y outputs	V <sub>CC</sub> = 3.135 V,	I <sub>OH</sub> = -1 mA	2.4			V	
		Y outputs	$V_{CC} = 3.135 \text{ V},$	I <sub>OL</sub> = 1 mA			0.4		
VOL	Low-level output voltage	SDATA	V <sub>CC</sub> = 3.135 V	$I_{OL} = 3 \text{ mA}$	0.1		0.4	V	
		SDATA	VCC = 3.133 V	I <sub>OL</sub> = 6 mA	0.2		0.6		
		SDATA	V <sub>CC</sub> = 3.135 V,	VO = NCC WAX			20	μΑ	
	High lovel output ourrent		V <sub>CC</sub> = 3.135 V,	V <sub>O</sub> = 2 V	-54		-126		
ЮН	High-level output current	Y outputs	V <sub>CC</sub> = 3.3 V,	V <sub>O</sub> = 2.6 V		-60		mA	
			V <sub>CC</sub> = 3.465 V,	V <sub>O</sub> = 3.135 V	-21		-46		
			$V_{CC} = 3.135 \text{ V},$	V <sub>O</sub> = 1 V	49		118		
lOL	IOL Low-level output current	Y outputs	$V_{CC} = 3.3 \text{ V},$	V <sub>O</sub> = 0.7 V		58		mA	
			$V_{CC} = 3.465 \text{ V},$	V <sub>O</sub> = 0.4 V	23		53		
		А		VI = ACC			5	μΑ	
۱н	High-level input current	OE	V <sub>CC</sub> = 3.465 V,				20		
		SCLOCK, SDATA					20		
		А					-5		
I <sub>I</sub> L	Low-level input current	OE	$V_{CC} = 3.465 \text{ V},$	$V_I = GND$	-10		-50	μΑ	
		SCLOCK, SDATA			-10		-50		
loz	High-impedance-state output	current	$V_{CC} = 3.465 \text{ V},$	V <sub>O</sub> = 3.465 V or 0			±10	μΑ	
loff	Off-state current	SCLOCK, SDATA	$V_{CC} = 0$ ,	V <sub>I</sub> = 0 V to 5.5 V			50	μΑ	
Icc	Supply current		V <sub>CC</sub> = 3.465 V,	IO = 0		0.2	0.5	mA	
ΔlCC	CC Change in supply current		$V_{CC} = 3.135 \text{ V to } 3.46$ One input at $V_{CC} = 0.0$ All other inputs at $V_{CC}$	6 V,			500	μА	
Ci	C <sub>i</sub> Input capacitiance		$V_I = V_{CC}$ or GND,	V <sub>C</sub> C = 3.3 V		4		pF	
Co	C <sub>O</sub> Output capacitance		$V_O = V_{CC}$ or GND,	V <sub>C</sub> C = 3.3 V		6		pF	
C <sub>I/O</sub>	SDATA I/O capacitance		$V_{I/O} = V_{CC}$ or GND,	V <sub>CC</sub> = 3.3 V		7		pF	



# **CDC319** 1-LINE TO 10-LINE CLOCK DRIVER WITH I<sup>2</sup>C CONTROL INTERFACE SCAS590 – DECEMBER 1997

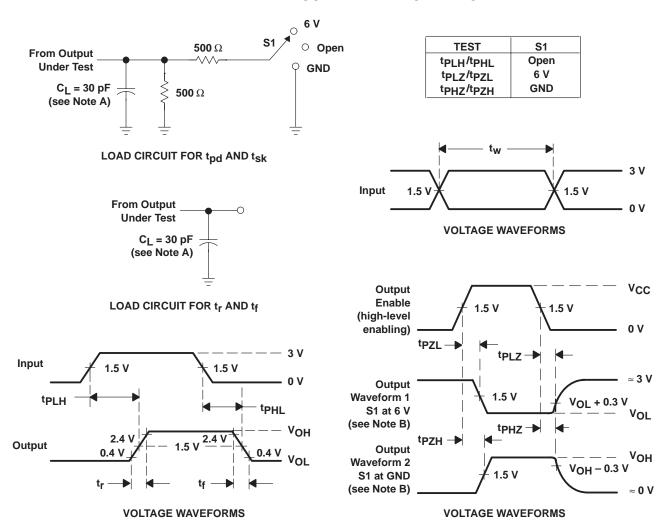
# switching characteristics over recommended operating conditions

	PARAMETER			то	TEST CONDITIONS	MIN	MAX	UNIT
			А	Υ		1.2	3.6	ns
<sup>t</sup> PLH	Low-to-high level propagation delay time		SCLOCK↓	SDATA valid	V <sub>CC</sub> = 3.3 V ±0.185 V, See Figure 3		2	μs
tPLH	Low-to-high level propagation of	delay time	SDATA↑	Υ	V <sub>CC</sub> = 3.3 V ±0.185 V, See Figure 3		150	ns
			А	Υ		1.2	3.6	ns
<sup>t</sup> PHL	High-to-low level propagation d	elay time	SCLOCK↓	SDATA valid	V <sub>CC</sub> = 3.3 V ±0.185 V, See Figure 3		2	μs
tPHL	High-to-low level propagation delay time		SDATA↑	Υ	$V_{CC} = 3.3 \text{ V} \pm 0.185 \text{ V},$ See Figure 3		150	ns
<sup>t</sup> PZH	Enable time to the high level		OE	Y		1	4.7	
t <sub>PZL</sub>	Enable time to the low level			Ť		1	4.7	ns
t <sub>PHZ</sub>	Disable time from the high level		OE	Y		1	4.7	ns
t <sub>PLZ</sub>	Disable time from the low level			ı ı		1	4.7	115
t <sub>sk(o)</sub>	Skew time		А	Υ			250	ps
t <sub>sk(p)</sub>	Skew time		А	Υ			500	ps
t <sub>sk(pr)</sub>	Skew time		А	Υ			1	ns
t <sub>r</sub>	Rise time			Υ		0.5	1.3	ns
	Rise time (see Note 4 and	SDATA			C <sub>L</sub> = 10 pF	6		ns
t <sub>r</sub>	Figure 3)	SDATA			$C_L = 400 \text{ pF}$		250	113
t <sub>f</sub>	Fall time			Υ		0.5	1.3	ns
+,	Fall time (see Note 4 and	SDATA			C <sub>L</sub> = 10 pF	20		ns
tf	Figure 3)	SDATA			C <sub>L</sub> = 400 pF		250	115

NOTE 4: This parameter has a lower limit than BUS specification. This allows use of series resistors for current spike protection.



### PARAMETER MEASUREMENT INFORMATION



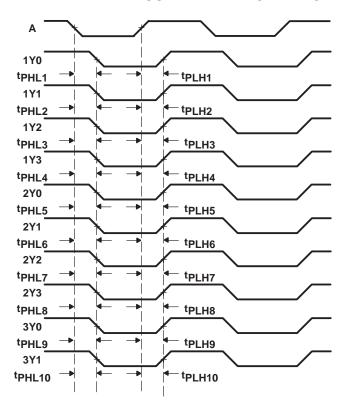
NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \,\Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

SCAS590 - DECEMBER 1997

### PARAMETER MEASUREMENT INFORMATION



NOTES: A. Output skew,  $t_{Sk(0)}$ , is calculated as the greater of:

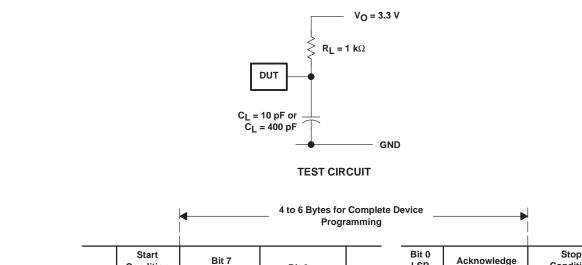
- The difference between the fastest and slowest of t<sub>PLHn</sub> (n = 1:10)
- The difference between the fastest and slowest of tpHLn (n = 1:10)
- B. Pulse skew,  $t_{sk(p)}$ , is calculated as the greater of  $|t_{PLHn} t_{PHLn}|$  (n = 1:10).
- C. Process skew, t<sub>sk(pr)</sub>, is calculated as the greater of:
  - The difference between the fastest and slowest of tpLHn (n = 1:10) across multiple devices under identical operating conditions
  - The difference between the fastest and slowest of tpHLn (n = 1:10) across multiple devices under identical operating conditions

Figure 2. Waveforms for Calculation of  $t_{sk(0)}$ ,  $t_{sk(p)}$ ,  $t_{sk(pr)}$ 

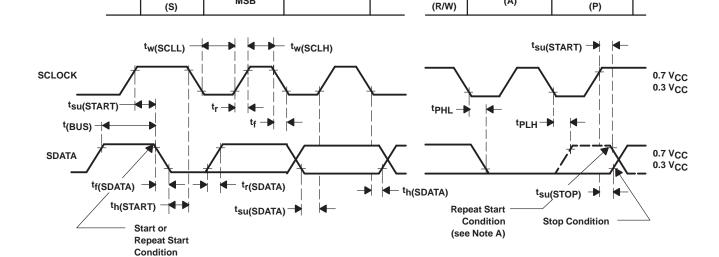


Condition

### PARAMETER MEASUREMENT INFORMATION



Bit 6



LSB

(A)

	•
BYTE	DESCRIPTION
1	I <sup>2</sup> C address
2	Command (dummy value, ignored)
3	Byte count (dummy value, ignored)
4	I <sup>2</sup> C data byte 0
5	I <sup>2</sup> C data byte 1
6	I <sup>2</sup> C data byte 2

**VOLTAGE WAVEFORMS** 

NOTES: A. The repeat start condition is not supported.

Condition

MSB

B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  100 kHz,  $Z_O = 50~\Omega$ ,  $t_f \geq$  10 ns.  $t_f \geq$  10 ns.

Figure 3. Propagation Delay Times, tr and tf



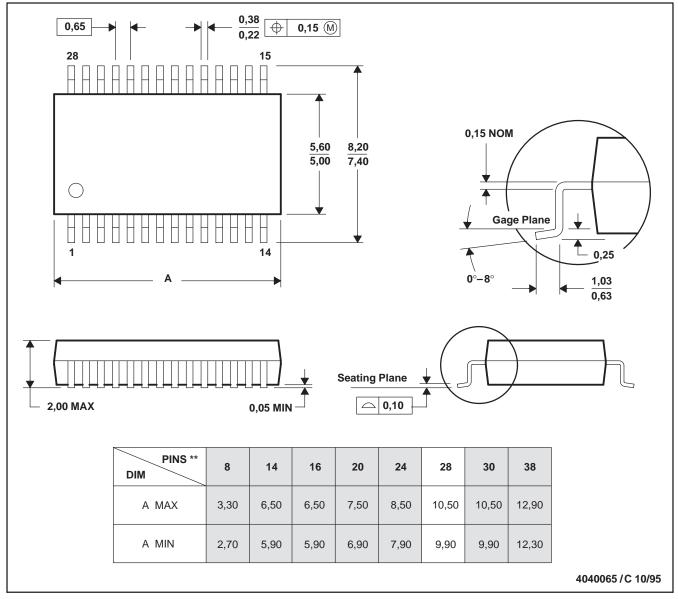
### **MECHANICAL INFORMATION**

### DB (R-PDSO-G\*\*)

SCAS590 - DECEMBER 1997

### PLASTIC SMALL-OUTLINE PACKAGE

### **28 PIN SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



#### **IMPORTANT NOTICE**

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated